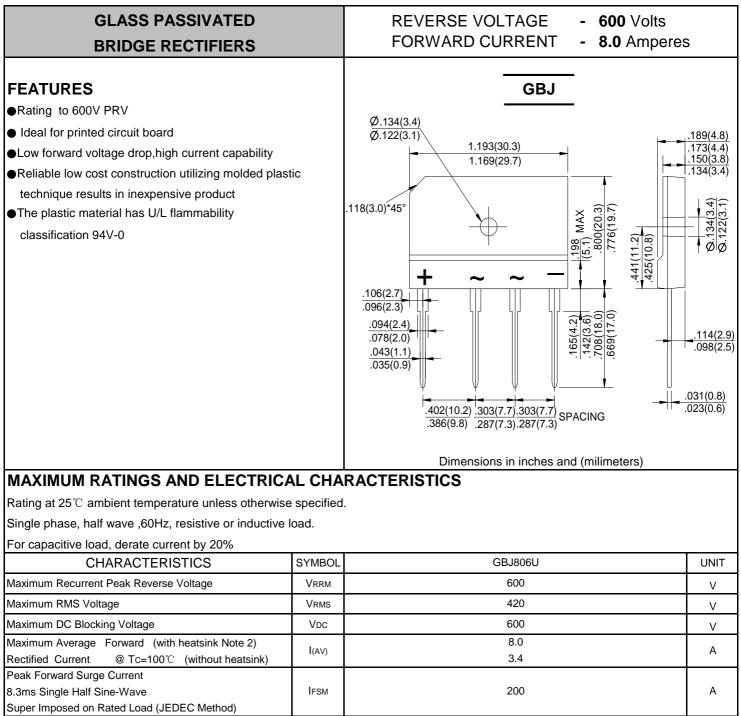


GBJ806U



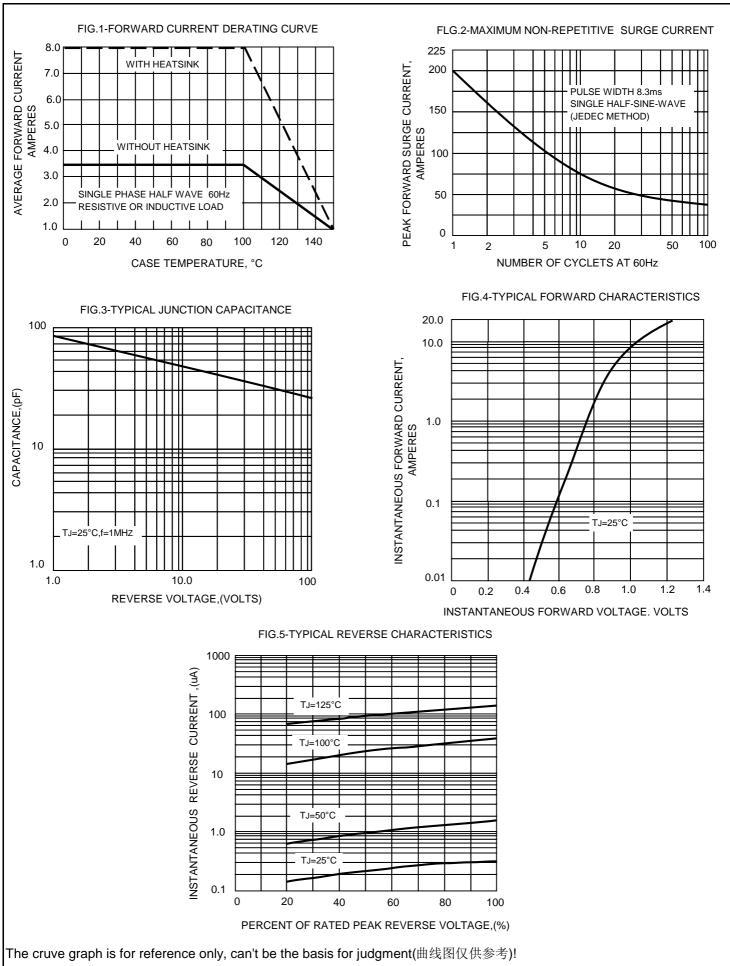
CHARACTERISTICS	SYMBOL	GBJ806U	UNIT
Maximum Recurrent Peak Reverse Voltage	Vrrm	600	V
Maximum RMS Voltage	Vrms	420	V
Maximum DC Blocking Voltage	VDC	600	V
Maximum Average Forward (with heatsink Note 2) Rectified Current @ Tc=100℃ (without heatsink)	I(AV)	8.0 3.4	А
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	Ігѕм	200	A
Typical Forward Voltage at 4.0A DC	VF	0.89	V
Maximum Forward Voltage at 4.0A DC	VF	0.9	V
Maximum DC Reverse Current@ TJ=25℃at Rated DC Blocking Voltage@ TJ=125℃	lr	10.0 500	μA
I ² t Rating for Fusing (t<8.3ms)	l ² t	166	A ² s
Typical Junction Capacitance Per Element (Note1)	Сл	55	pF
Typical Thermal Resistance	Rejc	1.8	°C/W
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	Тѕтс	-55 to +150	°C

NOTES: 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2.Device mounted on 75mm*75mm*1.6mm Cu plate heatsink.

3.The typical data above is for reference only(典型值仅供参考).

RATING AND CHARACTERTIC CURVES GBJ806U



REV. 2, 18-Aug-2015